NSN 5961-00-646-5599

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View Online at https://aerobasegroup.com/nsn/5961-00-646-5599 **Inclosure Material:** Metal **Overall Length:** 0.750 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-base, emitter open and 12.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator: Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release1416 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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